

HMHAA280

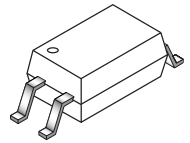
HMHA2801 SERIES

HMHA281

DESCRIPTION

The HMHA281, HMHA2801 Series consists of a gallium arsenide infrared emitting diode driving a silicon phototransistor in a compact 4-pin mini-flat package. The lead pitch is 1.27 mm.

The HMHAA280 series consists of two gallium arsenide infrared emitting diodes, connected in inverse parallel, driving a single silicon phototransistor in a compact 4-pin mini-flat package. The lead pitch is 1.27mm.



FEATURES

- Compact 4-pin package (2.4 mm maximum standoff height)
- Half pitch leads for optimum board space savings
- Current Transfer Ratio in selected groups
HMHA2801: 80-600%
HMHA2801A: 80-160%
HMHA2801B: 50-150%
HMHA2801C: 50-100%
HMHA281: 50-600%
HMHAA280: 50-600%
- Available in tape and reel quantities of 500 and 2500
- Applicable to Infrared Ray reflow (230°C Max, 30 seconds)
- BSI (File #8611/8612), CSA (File #1201524), UL (File #E90700) and VDE (File #136480) certified

APPLICATIONS

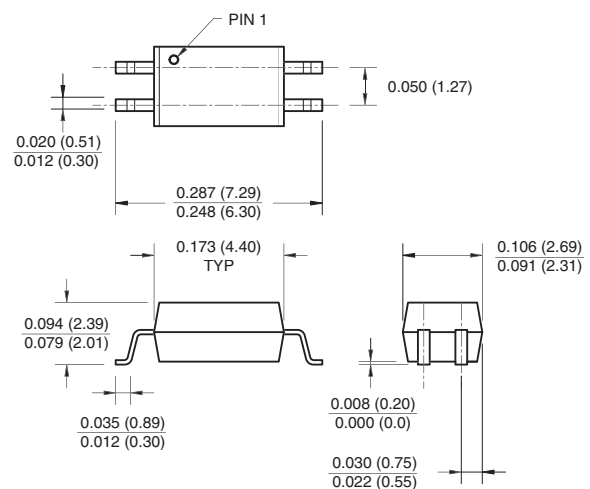
HMHAA280

- AC line monitor
- Unknown polarity DC sensor
- Telephone line receiver

HMHA281, HMHA2801 Series

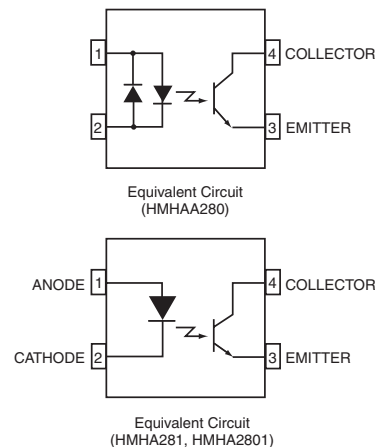
- Digital logic inputs
- Microprocessor inputs
- Power supply monitor
- Twisted pair line receiver
- Telephone line receiver

PACKAGE DIMENSIONS



NOTE

All dimensions are in inches (millimeters)



HMHAA280

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HMHA281

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)			
Parameter	Symbol	Value	Units
TOTAL PACKAGE			
Storage Temperature	T _{STG}	-40 to +125	°C
Operating Temperature	T _{OPR}	-40 to +100	°C
EMITTER			
Continuous Forward Current	I _{F (avg)}	50	mA
Peak Forward Current (1 μs pulse, 300 pps.)	I _{F (pk)}	1	A
Reverse Input Voltage (HMHA)	V _R	6	V
Power Dissipation	P _D	60	mW
Derate linearly (above 25°C)		0.6	mW/°C
DETECTOR			
Continuous Collector Current		50	mA
Power Dissipation	P _D	150	mW
Derate linearly (above 25°C)		1.5	mW/°C
Collector-Emitter Voltage	V _{CEO}	80	V
Emitter-Collector Voltage	V _{ECO}	7	V

ELECTRICAL CHARACTERISTICS (T _A = 25°C)							
INDIVIDUAL COMPONENT CHARACTERISTICS							
Parameter	Test Conditions	Symbol	Device	Min	Typ**	Max	Unit
EMITTER Forward Voltage	(I _F = 10 mA)	V _F	HMHA281	1.0		1.3	V
			HMHA2801				
			HMHA2801A	1.0		1.3	
			HMHA2801B				
	(I _F = 20 mA)		HMHA2801C		1.4		
	(I _F = ±5 mA)		HMHAA280		1.4		
Reverse Current	(V _R = 5 V)	I _R	All			5	µA
DETECTOR							
Breakdown Voltage Collector to Emitter	(I _C = 0.5 mA, I _F = 0)	BV _{CEO}	All	80			V
Emitter to Collector	(I _E = 100 µA, I _F = 0)	BV _{ECO}	All	7			
Collector Dark Current	(V _{CE} = 80 V, I _F = 0)	I _{CEO}	All			100	nA
Capacitance	(V _{CE} = 0 V, f = 1 MHz)	C _{CE}	All		10		pF

HMHAA280

HMHA2801 SERIES

HMHA281

TRANSFER CHARACTERISTICS (T _A = 25°C)							
Characteristic	Test Conditions	Symbol	Device	Min	Typ**	Max	Unit
DC Current Transfer Ratio	(I _F = ± 5 mA, V _{CE} = 5 V)	CTR	HMHAA280	50		600	%
	(I _F = 5 mA, V _{CE} = 5 V)		HMHA281	50		600	
			HMHA2801	80		600	
			HMHA2801A	80		160	
			HMHA2801B	50		150	
			HMHA2801C	50		100	
CTR Symmetry	(I _F = ± 5 mA, V _{CE} = 5 V)	—	HMHAA280	0.33		3.0	
Saturation Voltage	(I _F = ± 8 mA, I _C = 2.4 mA)	V _{CE (SAT)}	HMHAA280			0.4	V
	(I _F = 8 mA, I _C = 2.4 mA)		HMHA281			0.4	
	(I _F = 10 mA, I _C = 2 mA)		HMHA2801			0.3	
			HMHA2801A			0.3	
			HMHA2801B				
			HMHA2801C			0.2	
Rise Time (Non-Saturated)	(I _C = 2 mA, V _{CE} = 5 V) (R _L = 100Ω)	t _r	All except for HMHA2801C		3		μs
	(I _C = 2 mA, V _{CE} = 2V) (R _L = 1 KΩ)		HMHA2801C			9	
Fall Time (Non-Saturated)	(I _C = 2 mA, V _{CE} = 5 V) (R _L = 100Ω)	t _f	All except for HMHA2801C		3		
	(I _C = 2 mA, V _{CE} = 2V) (R _L = 1 KΩ)		HMHA2801C			9	

ISOLATION CHARACTERISTICS							
Characteristic	Test Conditions	Symbol	Device	Min	Typ**	Max	Unit
Steady State Isolation Voltage	(1 Minute)	V_{ISO}	All	2500			VRMS

** All typicals at $T_A = 25^\circ\text{C}$

HMHAA280

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HMHA281

TYPICAL PERFORMANCE CURVES

Fig. 1 Forward Current vs. Forward Voltage

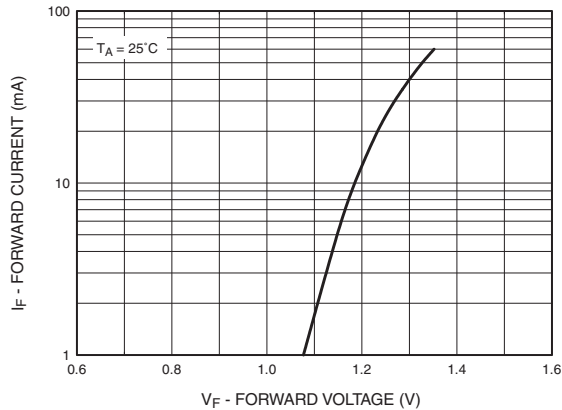


Fig. 2 Collector Current vs. Forward Current

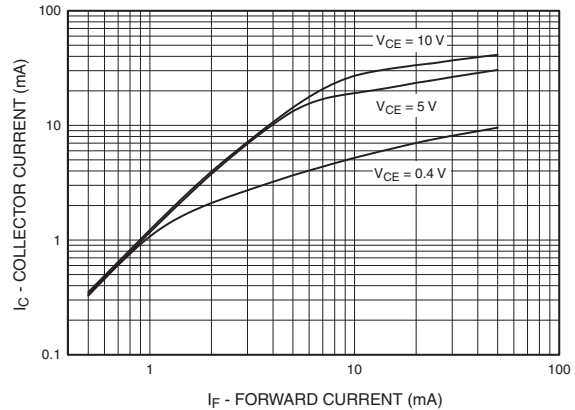


Fig. 3 Current Transfer Ratio vs. Forward Current

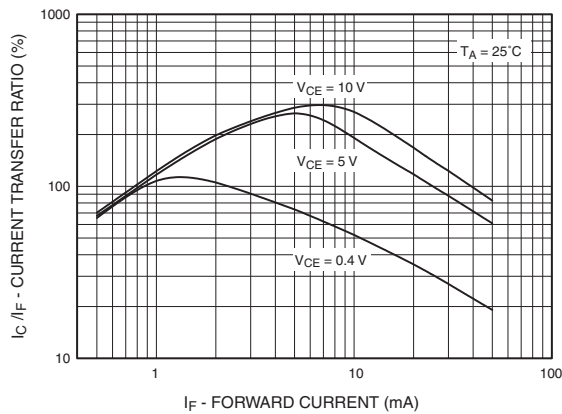


Fig. 4 Normalized CTR vs. Temperature

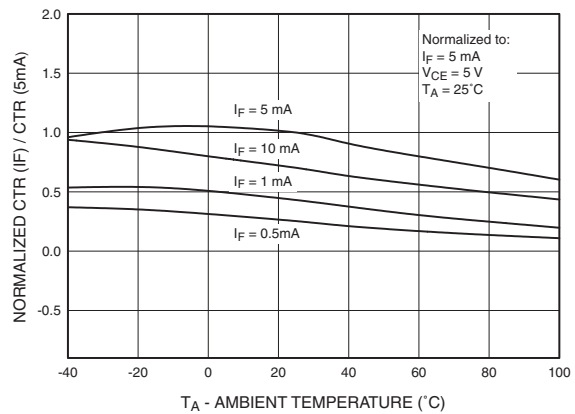


Fig. 5 Collector Current vs. Temperature

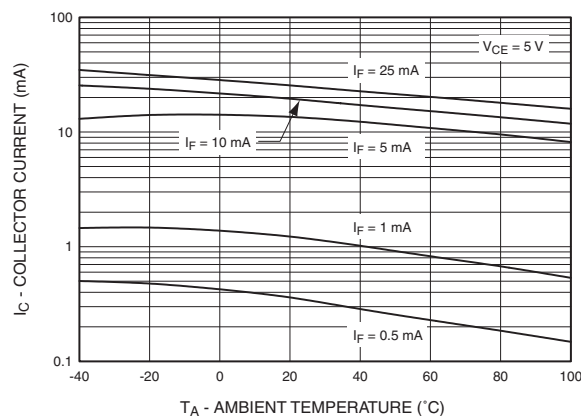


Fig. 6 Collector Current vs. Collector-Emitter Voltage

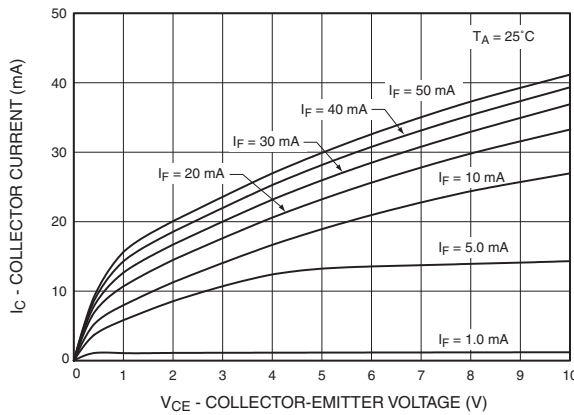


Fig. 7 Collector Current vs. Collector-Emitter Voltage

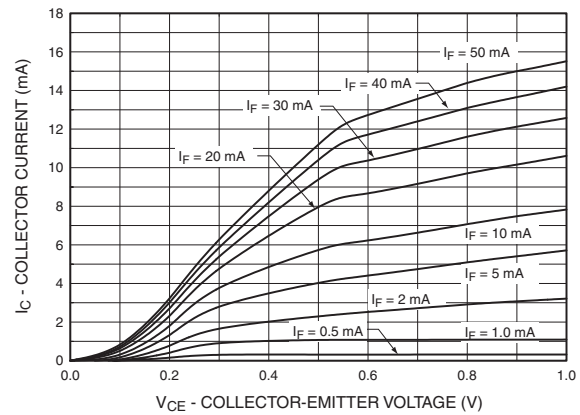


Fig. 8 Collector Dark Current vs. Temperature

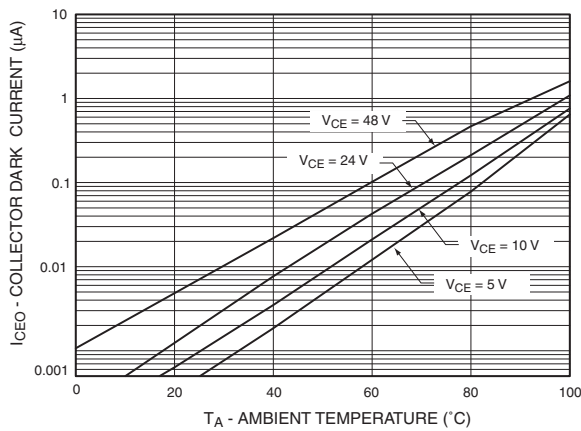


Fig. 9 Switching Time vs. Load Resistance

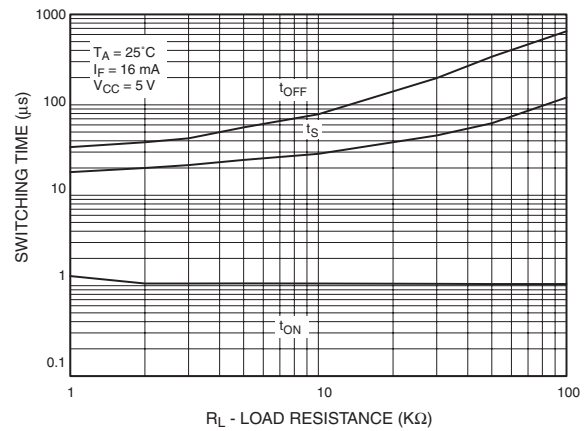
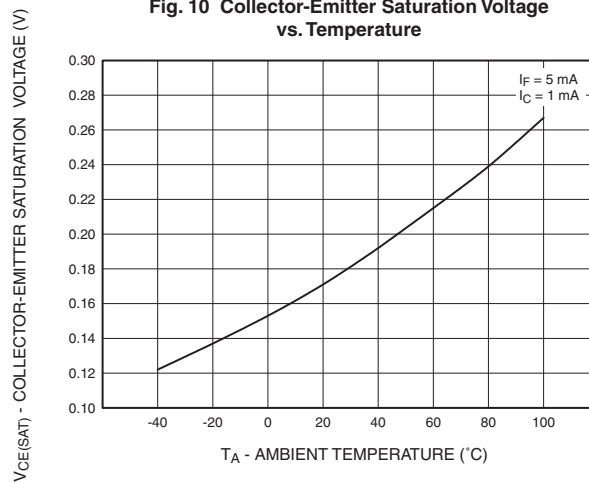


Fig. 10 Collector-Emitter Saturation Voltage vs. Temperature



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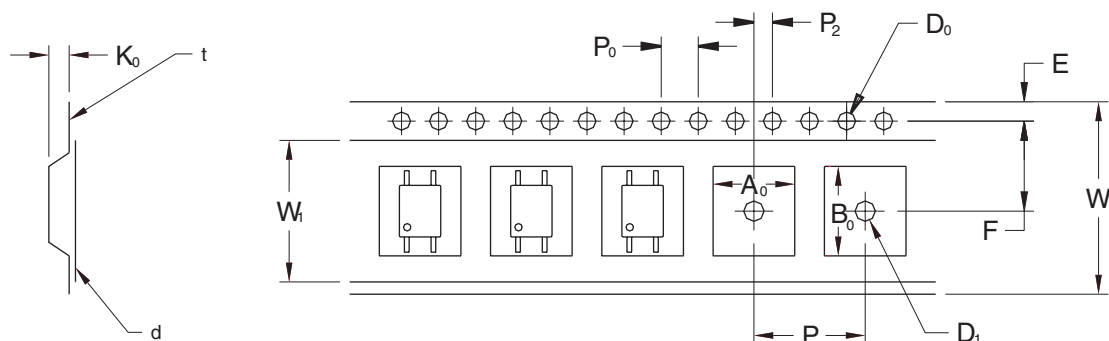
ORDERING INFORMATION

Option	Description
V	VDE Approved
R1	Tape and Reel (500 units)
R2	Tape and Reel (2500 units)
R3	Tape and Reel (500 units; unit 180° rotated)
R4	Tape and Reel (2500 units; unit 180° rotated)
R1V	Tape and Reel (500 units) and VDE Approved
R2V	Tape and Reel (2500 units) and VDE Approved
R3V	Tape and Reel (500 units; unit 180° rotated) and VDE Approved
R4V	Tape and Reel (2500 units; unit 180° rotated) and VDE Approved

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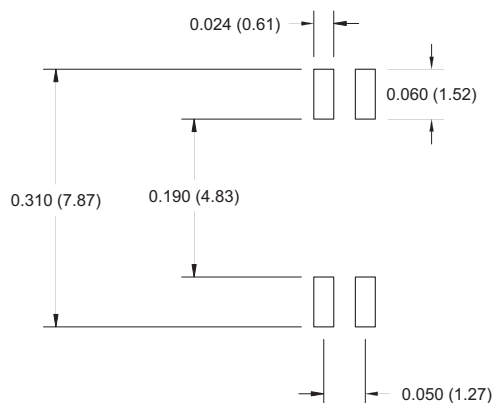
		1.27 Pitch
Description	Symbol	Dimensions (mm)
Tape Width	W	12.00±0.4
Tape Thickness	t	0.30±0.20
Sprocket Hole Pitch	P ₀	4.00±0.20
Sprocket Hole Dia.	D ₀	1.55±0.20
Sprocket Hole Location	E	1.75±0.20
Pocket Location	F	5.50±0.20
	P ₂	2.00±0.20
Pocket Pitch	P	8.00±0.20
Pocket Dimension	A ₀	4.40±0.20
	B ₀	7.30±0.20
	K ₀	2.30±0.20
Pocket Hole Dia.	D ₁	1.55±0.20
Cover Tape Width	W ₁	9.20
Cover Tape Thickness	d	0.065±0.02
Max. Component Rotation or Tilt		20° max
Devices Per Reel	R1	500
	R2	2500
Reel Diameter	R1	178 mm (7")
	R2	330 mm (13")

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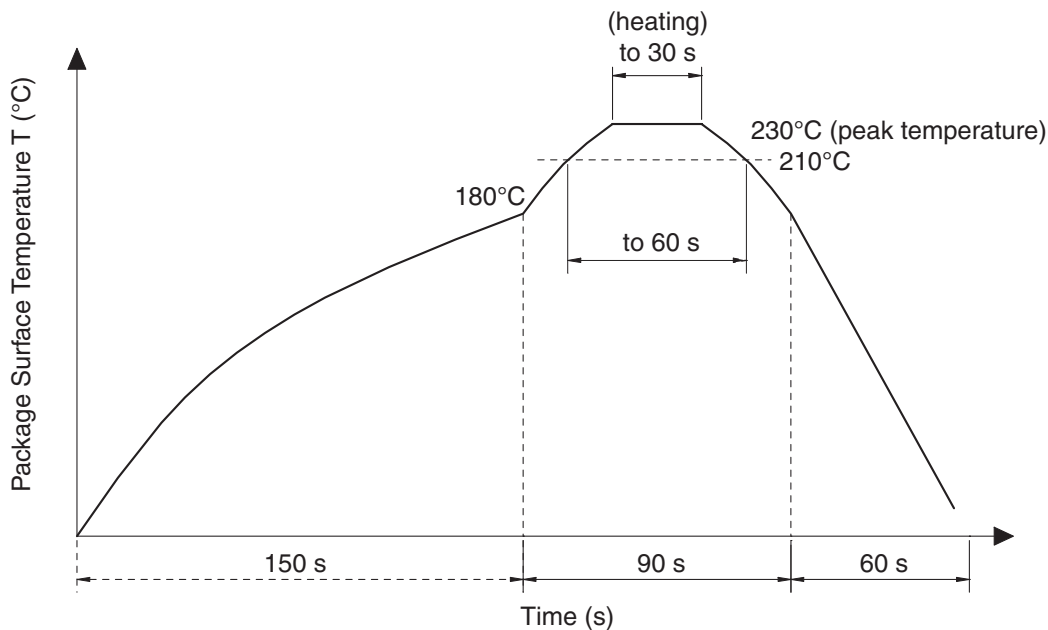
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HMHA281

Footprint Drawing for PCB Layout



Recommended Infrared Reflow Soldering Profile



- Peak reflow temperature: 230°C (package surface temperature) for 30 seconds
- Time of temperature higher than 210°C: 60 seconds or less
- One time soldering reflow is recommended

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HMHA281

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